#### **PHOTONIC** Silicon Photodiode, U.V. Enhanced Photoconductive DETECTORS INC. Type PDU-C102



#### PACKAGE DIMENSIONS INCH [mm] WINDOW CAP Ø0.184[4.67] (WELDED) 0.150[3.81] **0.040**[1.02] 0.060[1.52] Ø0.155[3.94 WIRE 0.500 BONDS [12.70] MIN 72 0.100[2.54] Ø0.210[5.33] VIEWING **\_\_\_**6 ANGLE 0.042 ANODE Ø0.018[0.46] HEADER [1.06] PHOTODIODE L<sub>CATHODE</sub> Ø0.018[0.46] 0.053[1.35] SQUARE 0.030[0.76] ACTIVE AREA **TO-46 HERMETIC CAN PACKAGE** 0.045[1.14] ACTIVE AREA ACTIVE AREA = $.87 \text{ mm}^2$

#### **FEATURES**

- High speed
- U.V. enhanced
- Low capacitance
- U.V. window

# DESCRIPTION

The **PDU-C102** is a silicon, PIN planar diffused, U.V. enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-46 metal can with a U.V. transmitting window.

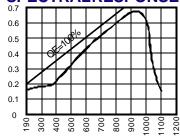
#### **APPLICATIONS**

- Spectrometers
- Fluorescent analysers
- U.V. meters
- Colorimeters

# ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V <sub>BR</sub>	Reverse Voltage		30	V
T <sub>STG</sub>	Storage Temperature	-55	+150	Ŷ
Τ <sub>ο</sub>	Operating Temperature Range	-40	+125	с
T <sub>s</sub>	Soldering Temperature*		+240	°C
Ι	Light Current		500	mA

## SPECTRALRESPONSE



WAVELENGTH(nm)

RESPONSIVITY (A/W)

\*1/16 inch from case for 3 secs max

## ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS				
ا <sub>عد</sub>	Short Circuit Current	H = 100 fc, 2850 K	8.5	9		μA				
I <sub>D</sub>	Dark Current	$H = 0, V_{R} = 5V$		45	150	pА				
R <sub>SH</sub>	Shunt Resistance	$H = 0, V_{R} = 10 \text{ mV}$	.25	1		GΩ				
TCR <sub>SH</sub>	RSH Temp. Coefficient	$H = 0, V_{R} = 10 \text{ mV}$		-8		% / °C				
CJ	Junction Capacitance	$H = 0, V_{R} = 5 V^{**}$		10		pF				
λrange	Spectral Application Range	Spot Scan	190		1100	nm				
R	Responsivity	$V_{R}$ = 0 V, $\lambda$ = 254 nm	.12	.18		A/W				
V <sub>BR</sub>	Breakdown Voltage	I = 10 μA	15	25		V				
NEP	Noise Equivalent Power	V <sub>R</sub> = 10 mV @ Peak		5x10 <sup>-14</sup>		W/√ <sup>Hz</sup>				
tr	Response Time	$RL = 1 K\Omega V_R = 5 V$		40		nS				

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. \*\*f=1 MHz [FORM NO. 100-PDU-C102 REV N/C]